

### LP5552 PWI 2.0 and PowerWise<sup>®</sup> Technology Compliant Energy Management Unit

#### **General Description**

The LP5552 is a PWI<sup>™</sup> 2.0 compliant Energy Management Unit (EMU) for reducing power consumption in low-power, portable applications.

The LP5552 contains 2 advanced, digitally controlled switching regulators for supplying variable voltages to a SoC or processor. The device also incorporates 5 programmable low-dropout, low-noise linear regulators for powering I/O, peripheral logic blocks, auxiliary system functions, and maintaining memory retention (dual-domains) in shutdown-mode.

The device is controlled via the high-speed serial PWI 2.0 open-standard interface. The LP5552 operates cooperatively with PowerWise® technology-compatible processors to optimize supply voltages adaptively (AVS - Adaptive Voltage Scaling) over process and temperature variations. It also supports dynamic voltage scaling (DVS) using frequency/voltage pairs from pre-characterized lookup tables.

### **Key Specifications**

- 2.7V to 4.8V Input Voltage Range
- ±2% (typical) Output Voltage Accuracy

#### Programmable DC/DC Buck Converters

- 800mA Output Current per Switcher
- Up to 88% Switcher Efficiency
- Digitally programmable from 0.6V 1.235V

#### Programmable LDOs

Five digitally programmable LDOs

#### **Features**

- High-efficiency PowerWise Technology Adaptive Voltage Scaling for intelligent energy management in AVS and DVS environments
- PWI 2.0 open standard interface for system-level power management
- Two digitally programmable 3.6MHz buck regulators to power dual-voltage domains
- Five programmable LDOs for system functions such as:
  PLL/Clock Generation
  - I/O
  - Memory Retention
- Internal soft start
- Variable regulator power up sequencing

### Applications

- GSM/GPRS/EDGE & UMTS cellular handsets
- Hand-held radios
- PDAs
- Battery-powered devices
- Portable instruments



### System Diagram



20210301

### **Connection Diagrams and Package Mark Information**



Note: The actual physical placement of the package marking will vary from part to part. The package markings "XYTT" designate assembly and manufacturing information. "XY" is a date code and "TT" is a NSC internal code for die traceability. Both will vary considerably. "SLKB" is an internal code that identifies the LP5552.



LP5552 Package Marking (The diamond denotes pin A1.)

**Ordering Information** 

Order Number	Package marking	Supplied As		
LP5552TL/NOPB	SLKB	250 units Tape and Reel		
LP5552TLX/NOPB	SLKB	3000 units Tape and Reel		

### **Pin Descriptions**

Pin #	Pin Name	I/O	Туре	Function
E2	DVDD1	Р	Р	Power supply voltage input for digital. Connect to VIN.
E6	DVDD2	Р	Р	Power supply voltage input for digital, LDO2, and LDO5. Connect to VIN.
B6	AVDD1	Р	Р	Power supply voltage input for analog, switching regulator #1, and LDO3. Connect to VIN.
B1	AVDD2	Р	Р	Power supply voltage input for analog, switching regulator #2, and LDO4. Connect to $V_{IN}$
D1	AVDD3	Р	Р	Power supply voltage input for analog, and LDO1. Connect to V <sub>IN</sub>
A6	PVDD1	Р	Р	Power supply voltage input to internal PFET of switching regulator #1. Connect to VIN.
A1	PVDD2	Р	Р	Power supply voltage input to internal PFET of switching regulator #2. Connect to VIN.
E4	DGND1	G	G	Digital Ground. Connect to system Ground.
F4	DGND2	G	G	Digital Ground. Connect to system Ground.
B4	AGND1	G	G	Analog Ground. Connect to system Ground.
B3	AGND2	G	G	Analog Ground. Connect to system Ground.
A4	PGND1	G	G	Power Ground. Connect to system Ground.
A3	PGND2	G	G	Power Ground. Connect to system Ground.
F3	SUB	G	G	Substrate Ground. Connect to system Ground.
C3	RGND	G	G	Reference/sense Ground. Should connect to the Ground node of the switching regulators output capacitors.
D5	ENABLE	1	D	Enable input. Set this digital input high for normal operation.
F2	SCLK	1	D	PowerWise Interface (PWI) clock input
F1	SPWI	I/O	D	PowerWise Interface (PWI) bi-directional data
E5	RESETN	1	D	Active low Reset input. Set this digital input high for normal operation.
F5	PWROK	0	D	Power OK indicator. This is a digital, active high output signal.
E1	VO1	Р	Р	LDO1 output voltage.
F6	VO2	Р	Р	LDO2 output voltage. PWI signals SCLK and SPWI reference voltage.
C6	VO3	Р	Р	LDO3 output voltage. Can be programmed to track V <sub>CORE1</sub> voltage.
C1	VO4	Р	Р	LDO4 output voltage. Can be programmed to track V <sub>CORE2</sub> voltage.
D6	VO5	Р	Р	LDO5 output voltage.
A5	SW1	Р	Р	V <sub>COBE1</sub> Switching node; connected to filter inductor.
A2	SW2	Р	Р	V <sub>CORE2</sub> Switching node; connected to filter inductor.
B5	VFB1	1	А	V <sub>CORE1</sub> Switcher analog feedback input. Connect to the V <sub>CORE1</sub> output voltage.
B2	VFB2	1	А	$V_{CORE2}$ Switcher analog feedback input. Connect to the $V_{CORE2}$ output voltage.
C4	GPO0	0	D/OD	General Purpose Output 0. Can be programmed as a CMOS output referenced to $V_{op}$ or as an open-drain output to a user selected voltage.
D4	GPO1	0	D/OD	General Purpose Output 1. Can be programmed as a CMOS output referenced to $V_{02}$ or as an open-drain output to a user selected voltage.
D3	GPO2	0	D/OD	General Purpose Output 2. Can be programmed as a CMOS output referenced to $V_{O2}$ or as an open-drain output to a user selected voltage.
C2	SA1		D	PWI Slave Address Bit 1. Tie to Ground or $V_{IN}$ for 0 or 1, respectively. (Note: SA0 is internal. '0' = Slave(N) = $V_{COBE1}$ ; '1' = Slave(N+1) = $V_{COBE2}$ )
D2	SA2	1	D	PWI Slave Address Bit 2. Tie to Ground or V <sub>ivi</sub> for 0 or 1. respectively.
F3	SA3	1	D	PWI Slave Address Bit 3 (MSB). Tie to Ground or V., for 0 or 1, respectively
C5	Reserved	G	G	Must be tied to Ground. Failure to do so may result in undefined behavior
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A: Analog Pin I: Input Pin D: Digital Pin I/O: Input/Output Pin G: Ground Pin O: Output Pin P: Power Pin OD: Open Drain Output Pin

### Absolute Maximum Ratings (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

V <sub>IN</sub> pins (All V <sub>DD</sub> pins)	-0.3V to +6.0V
SW1, SW2, V <sub>01</sub> , V <sub>02</sub> , V <sub>03</sub> , V <sub>04</sub> ,	
V <sub>05</sub> to GND	-0.3V to +(V <sub>IN</sub> +0.3)V
ENABLE, RESETN, SCLK, SA1, SA2, SA3	–0.3V to +(V <sub>IN</sub> +0.3)V
SPWI, PWROK, V <sub>FB1</sub> , V <sub>FB2</sub> , GPO0,	
GPO1, GPO2	–0.3V to +(V <sub>IN</sub> +0.3)V
Junction Temperature (T <sub>J-MAX</sub> )	+150°C
Storage Temperature Range	–65°C to +150°C
Max Continuous Power Dissipation	
P <sub>D-MAX</sub> (Notes 3, 4)	Internally limited
Maximum Lead Temperature	
(Soldering, 10 seconds)	+260°C
ESD Ratings (Note 5)	
All pins	2kV HBM

### **Operating Ratings** (Notes 1, 2)

Input voltage range V<sub>IN</sub> ENABLE, RESETN, PWROK SPWI, SCLK SA1, SA2, SA3

 $\begin{array}{c} \text{2.7V to } \text{4.8V} \\ \text{0V to } \text{V}_{\text{IN}} \text{ V} \\ \text{0V to } \text{V}_{\text{O2}} \text{ V} \\ \text{0V to } \text{V}_{\text{O2}} \text{ V} \end{array}$ 

### **Thermal Properties**

Junction Temperature (T <sub>J</sub> )	-40°C to +125°C
Ambient Temperature (T <sub>A</sub> )	
(Note 6)	-40°C to +85°C
Junction-to-Ambient Thermal	
Resistance ( $\theta_{JA}$ ) (Note 7)	60°C/W

### General Electrical Characteristics (Notes 2, 8, 9)

Unless otherwise noted,  $V_{IN} = 3.6V$ . Typical values and limits appearing in normal type apply for  $T_J = 25^{\circ}C$ . Limits appearing in **boldface** type apply over the entire junction temperature range for operation,  $-40^{\circ}C \le T_1 \le +125^{\circ}C$ .

200V MM

Symbol	Parameter	Conditions	Min	Тур	Max	Units
Ι <sub>α</sub>	Shutdown Supply Current	All circuits off; -40ºC ≤T <sub>A</sub> = T <sub>J</sub> ≤ +125ºC		1	75	
	Memory retention current in Deep Sleep (i.e., both slaves in Sleep state)	$V_{CORE1}$ and $V_{CORE2}$ in Sleep state; $V_{O1},V_{O2},$ and $V_{O5}$ on, but unloaded; $V_{03}$ and $V_{O4}$ in low $I_Q$		130	350	μA
	No load supply current	All regulators active and unloaded; switching regulators in Burst-PWM		735	930	
UVLO-high	Under Voltage Lockout, high threshold			2.6	2.7	V
UVLO-low	Under Voltage Lockout, low threshold		2.5	2.6		v
Thermal Shutdov	wn					
TSD	Threshold (Note 10) Hysteresis (Note 10)		160 20			°C
Logic and Contr	ol Inputs					
V <sub>IL</sub>	Logic Input Low	ENABLE, RESETN, SPWI, SCLK 2.7V ≤ V <sub>IN</sub> ≤ 4.8V			0.2	V
V <sub>IH-SIDEBAND</sub>	Logic Input High	ENABLE, RESETN 2.7V ≤ V <sub>IN</sub> ≤ 4.8V	2.0			V
V <sub>IH-PWI</sub>	Logic Input High	SPWI, SCLK 1.5V ≤ V <sub>O2</sub> ≤ 3.3V	V <sub>02</sub> -0.2			V
I <sub>IL</sub>	Input Leakage Current	ENABLE, RESETN 2.7V $\leq V_{IN} \leq 4.8V$	-1		+1	
	Input Leakage Current (Note: Largely due to pull-down resistors)	SPWI, SCLK 1.5V ≤ V <sub>O2</sub> ≤ 3.3V	-1		+5	μA
R <sub>PD-PWI</sub>	Pull-down resistance for PWI signals	SPWI, SCLK	0.5	1	2	MΩ

Symbol	Parameter	Conditions	Min	Тур	Max	Units
Logic and Co	ontrol Outputs	•				
V <sub>OL</sub>	Logic Output Low	PWROK, SPWI, GPOx				N
		I <sub>SINK</sub> ≤ 1mA			0.4	v
V <sub>OH-SIDEBAND</sub>	Logic Output High	PWROK	V 04			V
		I <sub>SOURCE</sub> ≤ 1mA	v <sub>IN</sub> -0.4			
V <sub>OH-PWI</sub>	Logic Output High	SPWI	V 04			V
		I <sub>SOURCE</sub> ≤ 1mA	V <sub>02</sub> -0.4			v
V <sub>OH-GPOx</sub>	Logic Output High	GPOx, GPOs set for CMOS out	V 04			v
		I <sub>SOURCE</sub> ≤ 1mA	v <sub>02</sub> -0.4			
V <sub>OD-GPOx</sub>	Maximum Open-Drain High Voltage	GPOx			V <sub>IN</sub> +0.3	V
I <sub>GPO</sub>	GPO Source/Sink Current			1		mA
T <sub>ENL</sub>	Minimum ENABLE low pulse		100			nS
	time		100			113
T <sub>RSTL</sub>	Minimum RESETN low pulse		100			nS

### Output Specification (Notes 2, 9)

Supply	Output Voltage Range (V)	Default Output Voltage (V)	Output Voltage Resolution (mV)	I <sub>MAX</sub> Maximum Output Current	Typical Application
				(mA)	
					Voltage Scaling Domain
V <sub>CORE1</sub>	0.6 to 1.235	1.235	5	800	1
					Voltage Scaling Domain
V <sub>CORE2</sub>	0.6 to 1.235	1.235	5	800	2
LDO1	0.7 to 2.2	1.2	100	100	PLL/Fixed Logic
LDO2	1.5 to 3.3	3.3	100-300	250	I/O Ring
					Embedded Memory
LDO3	0.6 to 1.35	1.25	50	50	Domain 1
					Embedded Memory
LDO4	0.6 to 1.35	1.25	50	50	Domain 2
LDO5	1.2 to 3.3	3.3	100-300	250	Peripheral(s)

 $V_{CORE1}/V_{CORE2}$  Switchers 1 and 2 Output Voltage Characteristics Unless otherwise noted,  $V_{IN} = 3.6V$ . Typical values and limits appearing in normal type apply for  $T_J = 25^{\circ}C$ . Limits appearing in **boldface** type apply over the entire junction temperature range for operation,  $-40^{\circ}C$  to  $+125^{\circ}C$ . (Notes 2, 8, 9)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V <sub>OUT</sub> Accuracy	Output voltage, Static accuracy	0.65V ≤ V <sub>OUT</sub> ≤ 1.235V I <sub>OUT</sub> = 0 - 800mA	-2		+2	9/
	Output voltage, Static accuracy	$0.60V \le V_{OUT} \le 0.65V$ $I_{OUT} = 0 - 800mA$	-4		+4	70
V <sub>OUT</sub> Range	Programmable Output Voltage Range	0mA ≤ I <sub>OUT</sub> ≤ 800mA	0.6	1.235 (default)	1.235	V
ΔV <sub>OUT</sub>	Line regulation	$2.7V \le V_{IN} \le 4.8V,$ $I_{OUT} = 100mA$		0.05		%/V
	Load regulation	100mA ≤ I <sub>OUT</sub> ≤ 800mA		0.001		%/mA
T <sub>SCALING</sub>	V <sub>OUT</sub> Setting Time	From min to max output voltage I <sub>OUT</sub> = 400mA			30	μS
Ι <sub>Q</sub>	Quiescent current	No Load, Burst-PWM Mode		325		μA
R <sub>DS-ON(P)</sub>	P-FET resistance	$V_{IN} = V_{SG} = 3.6V$		255		mΩ
R <sub>DS-ON(N)</sub>	N-FET resistance	$V_{IN} = V_{GS} = 3.6V$		135		mΩ
I <sub>OUT</sub>	Continuous load current		0		800	mA
I <sub>LIM</sub>	Peak switching current limit		850	1200	1560	mA
η	Efficiency peak	I <sub>OUT</sub> = 200mA, V <sub>IN</sub> = 2.7V, V <sub>COREx</sub> = 1.235V		88		%
f <sub>osc</sub>	Oscillator frequency	PWM-mode	3.45	3.6	3.75	MHz
C <sub>OUT</sub>	Output Filter Capacitance	0mA ≤ I <sub>OUT</sub> ≤ 800mA	7	10	13	μF
	Output Capacitor ESR		0		20	mΩ
L	Output Filter Inductance	0mA ≤ I <sub>OUT</sub> ≤ 800mA	0.7	1.0	1.3	μH
t <sub>ss</sub>	Soft start ramp time			120		μs
t <sub>START-UP</sub>	Start-Up Time from $V_{COREx}$ enable to $V_{OUT}$	V <sub>COREx</sub> = 1.235V, unloaded		200		μs

### V<sub>01</sub> LDO1 Output Voltage Characteristics

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Unless otherwise no	oted, $V_{IN} = 3.6$	V, V <sub>OUT</sub> = 1.2V (det	fault). Typical values and limits appearing in normal type apply for $T_J = 25^{\circ}C$ .
Limits appearing in	boldface type	apply over the full	operating junction temperature range, -40° to +125°C. (Notes 2, 8, 9)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V <sub>OUT</sub> Accuracy	Output Voltage	$1\text{mA} \le \text{I}_{\text{OUT}} \le 100\text{mA}, 2.7\text{V} \le \text{V}_{\text{IN}} \le 4.8\text{V}$	-2		2	%
V <sub>OUT</sub> Range	Programmable Output Voltage Range	0mA ≤ I <sub>OUT</sub> ≤ 100mA 16 steps of 100mV	0.7	1.2 (default)	2.2	v
I <sub>OUT</sub>	Output Current	$2.7V \le V_{IN} \le 4.8V$			100	
	Output Current Limit	V <sub>01</sub> = 0V (i.e., tied to Ground)			400	mA
l <sub>Q</sub>	Quiescent Current (Note 12)	I <sub>OUT</sub> = 50mA		19		μA
$\Delta V_{OUT}$	Line Regulation	$2.7V \le V_{IN} \le 4.8V$ $I_{OUT} = 50mA$	-0.1		0.1	%/V
	Load Regulation	$1 \text{mA} \le \text{I}_{\text{OUT}} \le 100 \text{mA}$	-0.005		0.005	%/mA
	Line Transient Regulation	$V_{IN} = 3.9V \rightarrow 3.6V \rightarrow 3.9V$ $T_{RISE} = T_{FALL} = 10\mu S$		10		mV
	Load Transient Regulation	$V_{IN} = 3.6V$ $I_{OUT} = 10mA → 90mA → 10mA$ $T_{RISE} = T_{FALL} = 10\mu S$		60		mV
e <sub>N</sub>	Output Noise Voltage	$10Hz \le f \le 100kHz$ $C_{OUT} = 2.2\mu F$		100		μVRMS
PSRR	Power Supply Ripple Rejection	f = 1kHz $C_{OUT} = 2.2\mu F$		50		dD
	Ratio	f = 10kHz C <sub>OUT</sub> = 2.2µF		40		UD
C <sub>OUT</sub>	Output Capacitance	$0mA \le I_{OUT} \le 100mA$	1	2.2	20	μF
	Output Capacitor ESR	ESR			500	mΩ
t <sub>START-UP</sub>	Start-Up Time from LDO1 enable	$C_{OUT} = 2.2 \mu F$ , $I_{OUT} = 100 mA$		50		μs

V <sub>02</sub> LDO2 (I/O	Supply)	Output	Voltage	Characteristics
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Unless otherwise noted,  $V_{IN} = 3.6V$ ,  $I_{OUT} = 125$ mA,  $V_{O2} = 3.3V$ . Typical values and limits appearing in normal type apply for  $T_J = 25^{\circ}$ C. Limits appearing in **boldface** type apply over the full operating junction temperature range, -40 to +125^{\circ}C. (Notes 2, 8, 9)

Symbol	Parameter	Conditions	Min	Тур	Max	Units	
V <sub>OUT</sub> Accuracy	Output Voltage	$1\text{mA} \le \text{I}_{\text{OUT}} \le 250\text{mA}, 3.6\text{V} \le \text{V}_{\text{IN}}$ 4.8V	-2		2	%	
V <sub>OUT</sub> Range	Programmable Output Voltage Range	1.5 through 2.3 in 100mV steps, 2.5, 2.8, 3.0V and 3.3V	1.5	3.3 (default)	3.3	V	
I <sub>OUT</sub>	Output Current	$(V_{O2} + 0.4)V \le V_{IN} \le 4.8V$			250	m۸	
	Output Current Limit	V <sub>O2</sub> = 0V (i.e., tied to Ground)			800		
V <sub>IN</sub> - V <sub>O2</sub>	Dropout Voltage (Note 11)	I <sub>OUT</sub> = 125mA		70	260	mV	
Ι <sub>Q</sub>	Quiescent Current (Note 12)	I <sub>OUT</sub> = 125mA		19		μA	
ΔV <sub>OUT</sub>	Line Regulation	$(V_{O2} + 0.4)V \le V_{IN} \le 4.8V$ $I_{OUT} = 125mA$	-0.1		0.1	%/V	
	Load Regulation	$V_{IN} = 3.6V$ 1mA $\leq I_{OUT} \leq 250$ mA	-0.005		+0.005	%/mA	
	Line Transient Regulation (Note 13)	$V_{IN} = 4.0V \rightarrow 3.6V \rightarrow 4.0V$ $V_{O2} = 3.3V$ $T_{RISE} = T_{FALL} = 10\mu S$		10		mV	
	Load Transient Regulation	V <sub>IN</sub> = 3.6V I <sub>OUT</sub> = 25mA→225mA→25mA T <sub>RISE</sub> = T <sub>FALL</sub> = 1µS		125		mV	
PSRR	Power Supply Ripple Rejection	f = 1kHz C <sub>OUT</sub> = 4.7μF		55		dD	
	Ratio	f = 10kHz C <sub>OUT</sub> = 4.7 $\mu$ F		40		uв	
C <sub>OUT</sub>	Output Capacitance	0mA ≤ I <sub>OUT</sub> ≤ 250mA	2	4.7	20	μF	
	Output Capacitor ESR		5		500	mΩ	
t <sub>START-UP</sub>	Start-Up Time from LDO2 enable	C <sub>OUT</sub> = 4.7µF, I <sub>OUT</sub> = 250mA		50		μs	

 $V_{O3}/V_{O4}$  LDO3 and LDO4 Output Voltage Characteristics Unless otherwise noted,  $V_{IN} = 3.6V$ . Typical values and limits appearing in normal type apply for  $T_J = 25^{\circ}$ C. Limits appearing in boldface type apply over the full operating junction temperature range, -40 to +125°C. (Notes 2, 8, 9)

Symbol	Parameter	Conditions	Min	Тур	Мах	Units
V <sub>OUT</sub> Accuracy	Active/Independent, High I <sub>Q</sub>	$I_{OUT} \le 50$ mA, 2.7V $\le V_{IN} \le 4.8$ V Low $I_Q$ bit is cleared	-2.5		2.5	9/
	Active/Independent, Low I <sub>Q</sub>	$I_{OUT} \le 5$ mA, 2.7V $\le V_{IN} \le 4.8$ V Low I <sub>Q</sub> bit is cleared	-2.5		2.5	70
V <sub>OFFSET</sub>	Active state offset from tracked $V_{CORE}$ Offset = $V_{O3} - V_{FB1}$ Offset = $V_{O4} - V_{FB2}$	$0mA \le I_{OUT} \le 50mA, V_{FB} = 0.9V$ 2.7V $\le V_{IN} \le 4.8V$	0	25	70	mV
V <sub>OUT</sub> Range	Programmable Output Voltage Range	16 steps of 50mV	0.6	1.25 (default)	1.35	V
IQ	Quiescent Current (Note 12)	Active state/Tracking mode I <sub>OUT</sub> = 10μA Low I <sub>Q</sub> bit is set		35		
		Sleep state or Active/Independent mode I <sub>OUT</sub> = 10µA Low I <sub>Q</sub> bit is set		10		μA
I <sub>OUT</sub>	Output Current Low I <sub>Q</sub> bit is cleared	$2.7V \le V_{IN} \le 4.8V$		50		
	Output Current Limit Active state/Tracking	$2.7V \le V_{IN} \le 4.8V$		50		•
	Output Current Sleep state/Tracking, Low I <sub>Q</sub> bit is set	$2.7V \le V_{\rm IN} \le 4.8V$		5		mA
	Output Current, Independent, Low I <sub>Q</sub> bit is set	$2.7V \le V_{IN} \le 4.8V$		5		
	Output Current Limit	V <sub>O2</sub> = 0V (i.e., tied to Ground)			420	
PSRR	Power Supply Ripple Rejection Ratio	f = 1 kHz $C_{OUT} = 1.0 \mu F$		37		dB
C <sub>OUT</sub>	Output Capacitance	$0mA \le I_{OUT} \le 5mA$	0.75	1	2.2	μF
	Output Capacitor ESR		5		500	mΩ
t <sub>START-UP</sub>	Start-Up Time from LDOx enable	$C_{OUT} = 1.0\mu F$ , $I_{OUT} = 20mA$		50		μs

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 $V_{05}$  LDO5 Output Voltage Characteristics Unless otherwise noted,  $V_{IN} = 3.6V$ ,  $I_{OUT} = 125$ mA,  $V_{02} = 3.3V$ . Typical values and limits appearing in normal type apply for  $T_J = 25^{\circ}$ C. Limits appearing in boldface type apply over the full operating junction temperature range, -40 to +125^{\circ}C. (Notes 2, 8, 9)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V <sub>OUT</sub> Accuracy	Output Voltage	$1\text{mA} \le \text{I}_{\text{OUT}} \le 250\text{mA}, \text{V}_{\text{O2}} = 3.3\text{V}$ $3.6\text{V} \le \text{V}_{\text{IN}} \le 4.8\text{V}$	-2		2	%
V <sub>OUT</sub> Range	Programmable Output Voltage Range	1.2 through 2.3 in 100mV steps, 2.5, 2.8, 3.0V, and 3.3V	1.2	3.3 (default)	3.3	V
I <sub>OUT</sub>	Output Current	$(V_{O5} + 0.4)V \le V_{IN} \le 4.8V$			250	m۸
	Output Current Limit	V <sub>05</sub> = 0V (i.e., tied to Ground)			800	mA
V <sub>IN</sub> - V <sub>O5</sub>	Dropout Voltage (Note 11)	I <sub>OUT</sub> = 125mA		70	260	mV
Ι <sub>Q</sub>	Quiescent Current (Note 12)	I <sub>OUT</sub> = 125mA		19		μA
ΔV <sub>OUT</sub>	Line Regulation	$(V_{O5} + 0.4)V \le V_{IN} \le 4.8V$ $I_{OUT} = 125mA$	-0.1		0.1	%/V
	Load Regulation	$V_{IN} = 3.6V$ 1mA $\leq I_{OUT} \leq 250$ mA	-0.005		0.005	%/mA
	Line Transient Regulation (Note 13)	$V_{IN} = 4.0V \rightarrow 3.6V \rightarrow 4.0V$ $V_{O5} = 3.3V$ $T_{BISE} = T_{FALL} = 10\mu S$		10		
	Load Transient Regulation	$V_{IN} = 3.6V$ $I_{OUT} = 25mA \rightarrow 225mA \rightarrow 25mA$ $T_{RISE} = T_{FALL} = 1\mu S$		125		- mV
PSRR	Power Supply Ripple Rejection	f = 1 kHz $C_{OUT} = 4.7 \mu F$		55		dP
	Ratio	f = 10 kHz $C_{OUT} = 4.7 \mu F$		40		uБ
C <sub>OUT</sub>	Output Capacitance	$0mA \le I_{OUT} \le 250mA$	2	4.7	20	μF
	Output Capacitor ESR		5		500	mΩ
t <sub>START-UP</sub>	Start-Up Time from LDO5 enable	$C_{OUT} = 4.7 \mu F$ , $I_{OUT} = 250 mA$		50		μs

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings are conditions under which operation of the device is guaranteed. Operating Ratings do not imply guaranteed performance limits. For guaranteed performance limits and associated test conditions, see the Electrical Characteristics tables.

Note 2: All voltages are with respect to the potential at the GND pins.

**Note 3:** The Absolute Maximum power dissipation depends on the ambient temperature and can be calculated using the formula:  $P = (T_J - T_A)/\theta_{JA}$  where  $T_J$  is the junction temperature,  $T_A$  is the ambient temperature, and  $\theta_{JA}$  is the junction-to-ambient thermal resistance.

Junction-to-ambient thermal resistance is highly application and board-layout dependent. In applications where high maximum power dissipation exists, special care must be paid to thermal dissipation issues in board design.

Note 4: Internal thermal shutdown circuitry protects the device from permanent damage. Thermal shutdown engages at  $T_J = 160^{\circ}C$  (typ.) and disengages at  $T_J = 140^{\circ}C$  (typ.).

Note 5: The human-body model is a 100pF capacitor discharged through a 1.5kΩ resistor into each pin. The machine model is a 200pF capacitor discharged directly into each pin. MIL-STD-883 3015.7.

**Note 6:** In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature may have to be derated. Maximum ambient temperature  $(T_{A-MAX})$  is dependent on the maximum operating junction temperature  $(T_{J-MAX-OP})$ , the maximum power dissipation of the device in the application ( $P_{D-MAX}$ ), and the junction-to ambient thermal resistance of the part/package in the application ( $\theta_{JA}$ ), as given by the following equation:  $T_{A-MAX} = T_{J-MAX-OP} - (\theta_{JA} \times P_{D-MAX})$ .

**Note 7:** Junction-to-ambient thermal resistance ( $\theta_{JA}$ ) is taken from a thermal modeling result, performed under the conditions and guidelines set forth in the JEDEC standard JESD51–3. The test board is a 4-layer FR-4 board.

Junction-to-ambient thermal resistance is highly application and board-layout dependent. In applications where high maximum power dissipation exists, special care must be paid to thermal dissipation issues in board design.

The value of  $\theta_{JA}$  of this product can vary significantly, depending on PCB material, layout, and environmental conditions. In applications where high maximum power dissipation exists (high  $V_{IN}$ , high  $I_{OUT}$ ), special care must be paid to thermal dissipation issues. For more information on these topics, please refer to *Application Note 1112: Micro SMD Wafer Level Chip Scale Package* and *Application Note 1610: LP5552 Evaluation Board*.

**Note 8:** All limits are guaranteed by design, test and/or statistical analysis. All electrical characteristics having room-temperature limits are tested during production with  $T_J = 25^{\circ}$ C. All hot and cold limits are guaranteed by correlating the electrical characteristics to process and temperature variations and applying statistical process control.

Note 9: Capacitors: Low-ESR Multi-Layer Ceramic Capacitors are (MLCCs) used in setting electrical characteristics.

Note 10: Guaranteed specifically by design.

Note 11: Dropout voltage is the input-to-output voltage difference at which the output voltage is 100mV below its nominal value. Other parameters are not guaranteed when the LDO is in dropout. This specification applies only when the output voltage is greater than 2.7V.

Note 12: Quiescent currents for LDO1 through LDO5 do not include shared blocks such as the bandgap reference.

Note 13: V<sub>IN</sub> for line transient is above the default 3.6V to allow for 400mV of headroom from V<sub>IN</sub> to V<sub>OUT</sub>.

# LP5552

### LP5552 - Typical Performance Characteristics

Unless otherwise specified:  $V_{IN} = 3.6V$ ,  $T_A = 25^{\circ}C$ , output voltages and external components are default values specified in electrical characteristics table.



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### LP5552 PWI Register Map

The PWI 2.0 standard defines 32 8-bit base registers, and up to 256 8-bit extended registers, on each PWI slave. The table below summarizes these registers and shows default register bit values after reset, as programmed by the factory. The following subsections provide additional details on the use of each individual register.

				Slave A	ddress [	N]					
				Base	Registers	5					
Register	Register	Register Usage	Туре	Reset	Default V	/alue					
Address	Name			7	6	5	4	3	2	1	0
0x00	R0	Core Voltage 1 Switcher #1	R/W	0 *	1	1	1	1	1	1	1
0x01	R1	Memory Voltage 1 Independent Mode	R/W	0 *	1	1	0	1	0 *	0 *	0 *
0x02	R2	LDO3 Memory Retention Voltage 1 Sleep State	R/W	0 *	1	1	0	1	0 *	0 *	0 *
0x03	R3	Status Register 1	R/O	0 *	0 *	0 *	0 *	1*	1*	1 *	1*
0x04	R4	Device Capability Register 1	R/O	0	0	0	0	0	0	1	0
0x05	R5	Not Implemented	N/A	-	-	-	-	-	-	-	-
0x06	R6	Not Implemented	N/A	-	-	-	-	-	-	-	-
0x07	R7	LDO2 voltage (I/O voltage)	R/W	0 *	1	1	1	1	0 *	0 *	0 *
0x08	R8	LDO1 voltage	R/W	0 *	0	1	0	1	0 *	0 *	0 *
0x09	R9	LDO5 voltage	R/W	0 *	1	1	1	1	0 *	0 *	0 *
0x0A	R10	Enable Control 1	R/W	0 *	1 V <sub>CORE1</sub> Enable	1 LDO3 Enable	1 LDO2 Enable	1 LDO1 Enable	1 LDO5 Enable	0*	0 Force PWM Switcher #1
0x0B	R11	Not Implemented	N/A	-	-	-	-	-	-	-	-
0x0C	R12	GPO Data Register	R/W	0 *	0 *	0 *	0 *	0 *	0 GP2	0 GP1	0 GP0
0x0D	R13	Miscellaneous Control 1	R/W	0*	0*	0*	0*	1 GPO Open Drain Select	0 SW1 Slew Control	0 LDO3 Track Select	0 LDO3 Low IQ Bit
0x0E-0x1E	R14-R30	Not Implemented	N/A	-	-	-	-	-	-	-	-
0x1F	R31	Reserved Do not write to	Res.	-	-	-	-	-	-	-	-
		•		Extende	d Registe	ers	3		3		•
0x00-0xFF	ER0- ER255	Extended Register Space Not Implemented	N/A	-	-	-	-	-	-	-	-

			;	Slave A	ddress [N	l+1]					
				Base	Register	s					
Register	Register	Register Usage	Туре	Reset	t Default \	/alue					
Address	Name			7	6	5	4	3	2	1	0
0x00	R0	Core Voltage 2 Switcher #2	R/W	0 *	1	1	1	1	1	1	1
0x01	R1	Memory Voltage 2 Independent Mode	R/W	0 *	1	1	0	1	0 *	0 *	0*
0x02	R2	LDO4 Memory Retention Voltage 2 Sleep State	R/W	0 *	1	1	0	1	0 *	0 *	0 *
0x03	R3	Status Register 2	R/O	0 *	0 *	0 *	0 *	1 *	1 *	1*	1 *
0x04	R4	Device Capability Register 2	R/O	0	0	0	0	0	0	1	0
0x05-0x09	R5-R9	Not Implemented	N/A	-	-	-	-	-	-	-	-
0x0A	R10	Enable Control 2	R/W	0*	1 V <sub>CORE2</sub> Enable	1 LDO4 Enable	0*	0*	0*	0*	0 Force PWM Switcher #2
0x0B-0x0 C	R11-R12	Not Implemented	N/A	-	-	-	-	-	-	-	-
0x0D	R13	Miscellaneous Control 2	R/W	0 *	0*	0*	0*	0*	0 SW2 Slew Control	0 LDO4 Track Select	0 LDO4 Low IQ Bit
0x0E-0x1F	R14-R31	Not Implemented	N/A	-	-	-	-	-	-	-	-
				Extend	ed Regist	ers					
0x00-0xFF	ER0- ER255	Extended Register Space Not Implemented	N/A	-	-	-	-	-	-	-	-

Note: A bit with an asterisk (\*) denotes a register bit that is always read as a fixed value. Writes to these bits will be ignored. A bit with a hyphen (-) denotes a bit in an unimplemented register location. A write into unimplemented register(s) will be ignored. A read of an unimplemented register(s) will produce a "No response frame". Please refer to PWI specification version 2.0 for further information.

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### Slave Address [N] - 1st Slave Device R0 - V<sub>CORE1</sub> - Core Voltage 1

Address	0x00
Slave Address	Ν
Туре	R/W
Reset Default	8h'7F

Bit	Field Name	Description or Comment		
7	Sign	This bit is fixed to '0'. Reading this bit will result in a '0'. Any data written into this bit position using the Register Write command is ignored.		
6:0	Voltage	Programmed voltage value. Default value is in <b>bold.</b>		
		Voltage Data Code [6:0]	Voltage Value (V)	
		7h'00	0.60	
		7h'xx Linear scaling		
		7h'7F	1.235 (default)	

## R1 - $V_{O3}$ - LDO3 Memory Voltage 1 - Independent Mode

Address	0x01
Slave Address	Ν
Туре	R/W
Reset Default	8h'68

Bit	Field Name	Description or Comment				
7	Sign	This bit is fixed to '0'. Reading this bit will result in a '0'. Any data written into this bit pos using the Register Write command is ignored.				
6:3	Voltage	Programmed voltage value. A code of all ones indicates maximum voltage while a code of all zero indicates minimum voltage. Default value is in <b>bold</b> .				
		Voltage Data Code [6:3]	Voltage Value (volts)			
		4h'0	0.60			
		4h'1	0.65			
		4h'2	0.70			
		4h'3	0.75			
		4h'4	0.80			
		4h'5	0.85			
		4h'6	0.90			
		4h'7	0.95			
		4h'8	1.00			
		4h'9	1.05			
		4h'A	1.10			
		4h'B	1.15			
		4h'C	1.20			
		4h'D	1.25 (default)			
		4h'E	1.30			
		4h'F	1.35			
2:0	Unused	These bits are fixed to '0'. Reading these bits w bits using the Register Write command is ignore	vill result in a '000'. Any data written into these ed.			

### R2 - $V_{O3}$ - LDO3 Memory Retention Voltage 1 - Sleep State Value

0x02
Ν
R/W
8h'68

Bit	Field Name	Description or Comment				
7	Sign	This bit is fixed to '0'. Reading this bit will result	in a '0'. Any data written into this bit position			
		using the Register Write command is ignored.				
6:3	Voltage	Programmed voltage value. A code of all ones	indicates maximum voltage while a code of all			
		zero indicates minimum voltage. Default value i	es minimum voltage. Default value is in <b>bold.</b>			
		Voltage Data Code [6:3]	Voltage Value (volts)			
		4h'0	0.6			
		4h'1	0.65			
		4h'2	0.70			
		4h'3	0.75			
		4h'4	0.80			
		4h'5	0.85			
		4h'6	0.90			
		4h'7	0.95			
		4h'8	1.00			
		4h'9	1.05			
		4h'A	1.10			
		4h'B	1.15			
		4h'C	1.20			
		4h'D	1.25 (default)			
		4h'E	1.30			
		4h'F	1.35			
2:0	Unused	These bits are fixed to '0'. Reading these bits w	vill result in a '000'. Any data written into these			
		bits using the Register Write command is ignore	ed.			

### R3 - Status Register 1

Address	0x03
Slave Address	Ν
Туре	Read Only
Reset Default	8h'0F

Bit	Field Name	Description or Comment
7:4	Unused	Unused, read returns 0.
3:0	Unused	Unused, read returns 1.

### R4 - Device Capability Register 1

Address	0x04
Slave Address	Ν
Туре	Read Only
Reset Default	8h'02

Bit	Field Name	Description or Comment
7:3	Optional Function	Extended Register Read and Write are not supported by LP5552, read returns '0'.
	Support	
3:0	Version	Read transaction will return 0x2 indicating PWI 2.0 specification. Write transactions to this register are ignored.

### R7 - V<sub>02</sub> - LDO2 Voltage

Address	0x07
Slave Address	Ν
Туре	R/W
Reset Default	8h'78

Bit	Field Name	Description or Comment	
7 Sign This bit is fixed to '0'. Reading this bit will result in a '0'. Any data written ir using the Register Write command is ignored.		in a '0'. Any data written into this bit position	
6:3	Voltage	Programmed voltage value. A code of all ones zero indicates minimum voltage. Default value	indicates maximum voltage while a code of all is in <b>bold.</b>
		Voltage Data Code [6:3]	Voltage Value (volts)
		4h'0	1.5
		4h'1	1.5
		4h'2	1.5
		4h'3	1.5
		4h'4	1.6
		4h'5	1.7
		4h'6	1.8
		4h'7	1.9
		4h'8	2.0
		4h'9	2.1
		4h'A	2.2
		4h'B	2.3
		4h'C	2.5
		4h'D	2.8
		4h'E	3.0
		4h'F	3.3 (default)
2:0	Unused	These bits are fixed to '0'. Reading these bits w	vill result in a '000'. Any data written into these

### R8 - V<sub>01</sub> - LDO1 Voltage

Address	0x08
Slave Address	Ν
Туре	R/W
Reset Default	8h'28

ы	Field Name	Description or Comment	
7	Sign	This bit is fixed to '0'. Reading this bit will result	t in a '0'. Any data written into this bit position
		using the Register Write command is ignored.	
6:3 V	Voltage	Programmed voltage value. A code of all ones zero indicates minimum voltage. Default value	indicates maximum voltage while a code of all is in <b>bold.</b>
		Voltage Data Code [6:3]	Voltage Value (volts)
		4h'0	0.7
		4h'1	0.8
		4h'2	0.9
		4h'3	1.0
		4h'4	1.1
		4h'5	1.2 (default)
		4h'6	1.3
		4h'7	1.4
		4h'8	1.5
		4h'9	1.6
		4h'A	1.7
		4h'B	1.8
		4h'C	1.9
		4h'D	2.0
		4h'E	2.1
		4h'F	2.2

# R9 - V<sub>05</sub> - LDO5 Voltage

Address	0x09
Slave Address	Ν
Туре	R/W
Reset Default	8h'78

Bit	Field Name	Description or Comment	
7 Sign This bit is fixed to '0'. Reading this bit will result in a '0'. Any data writt		in a '0'. Any data written into this bit position	
		using the Register Write command is ignored.	
6:3 Voltage		Programmed voltage value. A code of all ones zero indicates minimum voltage. Default value i	indicates maximum voltage while a code of all is in <b>bold.</b>
		Voltage Data Code [6:3]	Voltage Value (volts)
		4h'0	1.2
		4h'1	1.3
		4h'2	1.4
		4h'3	1.5
		4h'4	1.6
		4h'5	1.7
		4h'6	1.8
		4h'7	1.9
		4h'8	2.0
		4h'9	2.1
		4h'A	2.2
		4h'B	2.3
		4h'C	2.5
		4h'D	2.8
		4h'E	3.0
		4h'F	3.3 (default)
2:0	Unused	These bits are fixed to '0'. Reading these bits w	vill result in a '000'. Any data written into these

### R10 - Enable Control Register 1

0x0A
Ν
R/W
8h'7C

Bit	Field Name	Description or Comment
7	Unused	This bit is fixed to '0'. Reading this bit will result in a '0'. Any data written into this bit position
		using the Register Write command is ignored.
6	R0, Core Voltage 1	1 : regulator is enabled (default)
	Enable	0 : regulator is disabled
5	R2, LDO3 Voltage	1 : regulator is enabled (default)
	Enable	0 : regulator is disabled
4	R7, LDO2 Voltage	1 : regulator is enabled (default)
	Enable	0 : regulator is disabled
3	R8, LDO1 Voltage	1 : regulator is enabled (default)
	Enable	0 : regulator is disabled
2	R9, LDO5 Voltage	1 : regulator is enabled (default)
	Enable	0 : regulator is disabled
1	Unused	This bit is fixed to '0'. Reading this bit will result in a '0'. Any data written into this bit position
		using the Register Write command is ignored.
0	Forced PWM Mode	0 : Intelligent and Automatic PWM/Burst-PWM Transition - Most Energy Efficient (default)
	— Switcher #1	1 : Forced PWM - No Burst Mode Allowed - Smallest Voltage Ripple

### R12 - GPO Data Register

Address	0x0C
Slave Address	Ν
Туре	R/W
Reset Default	8h'00

Bit	Field Name	Description or Comment
7:3	Unused	These bits are fixed to '0'. Reading these bits will result in a '00000'. Any data written into these
		bits using the Register Write command is ignored.
2	GPO2	General purpose output - digital.
		This bit is drives the GP2 pin
1	GPO1	General purpose output - digital.
		This bit is drives the G1 pin
0	GPO0	General purpose output - digital.
		This bit is drives the GP0 pin

### R13 - Misc Control Register 1

Address	0x0D
Slave Address	Ν
Туре	R/W
Reset Default	8h'08

Bit	Field Name	Description or Comment
7:4	Unused	These bits are fixed to '0'. Reading these bits will result in a '0000'. Any data written into these bits using the Register Write command is ignored.
3	GPO Open Drain Select	'0': GPOs will behave as push-pull CMOS outputs referenced to VO2 '1': GPOs will act as open-drain outputs (default)
2	SW1 Slew Control	'0': No slew rate restriction on VCORE1 switcher output voltage (default) '1': Slew rate of VCORE1 switcher output voltage is reduced
1	LDO3 Tracking Select	'0': LDO3 at R1 register value in Active mode. LDO3 does not track VCORE1 (default) '1': LDO3 tracks VCORE1 with offset
0	LDO3 Low I <sub>Q</sub> Bit	<ul><li>'0': Selects the higher bias point for LDO3 which results in 50mA operation (default)</li><li>'1': Selects the lower bias point for LDO3 which results in 5mA operation</li><li>See <i>Table 3</i> for a more detailed explanation of this bit</li></ul>

### **R31 - Reserved**

Address		0x1F
Slave A	ddress	Ν
Туре		Reserved
Reset D	efault	8h'00
Bit	Field Name	Description or Comment
7:0	Reserved	This register is reserved. The user should avoid accessing this register to prevent undefined behavior of the LP5552.

### Slave Address [N+1] - 2nd Slave Device - R0 - V<sub>CORE2</sub> - Core Voltage 2

Address	0x00
Slave Address	N + 1
Туре	R/W
Reset Default	8h'7F

Bit	Field Name	Description or Comment	
7	Sign	This bit is fixed to '0'. Reading this bit will resulusing the Register Write command is ignored.	t in a '0'. Any data written into this bit position
6:0	Voltage	Programmed voltage value. Default value is in <b>bold.</b>	
		Voltage Data Code [6:0]	Voltage Value (V)
		7h'00	0.60
		7h'xx	Linear scaling
		7h'7F	1.235 (default)

## R1 - V<sub>04</sub> - LDO4 Memory Voltage 2 - Independent Mode

0x01
N + 1
R/W
8h'68

Sign Voltage	This bit is fixed to '0'. Reading this bit will result using the Register Write command is ignored.      Programmed voltage value. A code of all ones zero indicates minimum voltage. Default value      Voltage Data Code [6:3]      4h'0      4h'1      4h'2      4h'3	t in a '0'. Any data written into this bit position indicates maximum voltage while a code of all is in <b>bold.</b> Voltage Value (volts) 0.60 0.65 0.70
Voltage	using the Register Write command is ignored.      Programmed voltage value. A code of all ones zero indicates minimum voltage. Default value      Voltage Data Code [6:3]      4h'0      4h'1      4h'2      4h'3	indicates maximum voltage while a code of all is in <b>bold.</b> Voltage Value (volts) 0.60 0.65 0.70
Voltage	Programmed voltage value. A code of all ones zero indicates minimum voltage. Default value Voltage Data Code [6:3] 4h'0 4h'1 4h'2 4h'3	indicates maximum voltage while a code of all is in <b>bold.</b> Voltage Value (volts) 0.60 0.65 0.70
	Voltage Data Code [6:3]        4h'0        4h'1        4h'2        4h'3	Voltage Value (volts) 0.60 0.65 0.70 0.75
	4h'0 4h'1 4h'2 4h'3	0.60 0.65 0.70
	4h'1 4h'2 4h'3	0.65 0.70 0.75
	4h'2 4h'3	0.70
	4h'3	0.75
		0.75
	4h'4	0.80
	4h'5	0.85
	4h'6	0.90
	4h'7	0.95
	4h'8	1.00
	4h'9	1.05
	4h'A	1.10
	4h'B	1.15
	4h'C	1.20
	4h'D	1.25 (default)
	4h'E	1.30
	4h'F	1.35
l	Jnused	4h'5        4h'6        4h'7        4h'8        4h'9        4h'A        4h'B        4h'C        4h'E        4h'F        Jnused        These bits are fixed to '0'. Reading these bits v        bits using the Register Write command is ignored to the set of th

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### R2 - V<sub>04</sub> - LDO4 Memory Retention Voltage 2 - Sleep State Value

Address	0x02
Slave Address	N + 1
Туре	R/W
Reset Default	8h'68

Bit	Field Name	Description or Comment	
7	Sign	This bit is fixed to '0'. Reading this bit will result in a '0'. Any data written into this bit position	
		using the Register Write command is ignored.	
6.3	Voltage	Programmed voltage value. A code of all ones i	indicates maximum voltage while a code of all
		Voltage Data Code [6:3]	Voltage Value (volts)
		4h'0	0.6
		4h'1	0.65
		4h'2	0.70
		4h'3	0.75
		4h'4	0.80
		4h'5	0.85
		4h'6	0.90
		4h'7	0.95
		4h'8	1.00
		4h'9	1.05
		4h'A	1.10
		4h'B	1.15
		4h'C	1.20
		4h'D	1.25 (default)
		4h'E	1.30
		4h'F	1.35
2:0	Unused	These bits are fixed to '0'. Reading these bits w bits using the Register Write command is ignore	vill result in a '000'. Any data written into these

### R3 - Status Register 2

Address	0x03
Slave Address	N + 1
Туре	Read Only
Reset Default	8h'0F

Bit	Field Name	Description or Comment
7:4	Unused	Unused, read returns 0.
3:0	Unused	Unused, read returns 1.

### R4 - Device Capability Register 2

Address	0x04
Slave Address	N + 1
Туре	Read Only
Reset Default	8h'02

Bit	Field Name	Description or Comment
7:3	Optional Function	Extended Register Read and Write are not supported by LP5552, read returns '0'.
	Support	
2:0	Version	Read transaction will return 0x2 indicating PWI 2.0 specification. Write transactions to this register are ignored.

### R10 - Enable Control Register 2

Address	0x0A
Slave Address	N + 1
Туре	R/W
Reset Default	8h'60

Bit	Field Name	Description or Comment
7	Unused	This bit is fixed to '0'. Reading this bit will result in a '0'. Any data written into this bit position using the Register Write command is ignored.
6	R0, Core Voltage 2 Enable	1 : regulator is enabled (default) 0 : regulator is disabled
5	R2, LDO4 Voltage Enable	1 : regulator is enabled (default) 0 : regulator is disabled
4:1	Unused	These bits are fixed to '0'. Reading these bits will result in a '000'. Any data written into these bits using the Register Write command is ignored.
0	Forced PWM Mode - Switcher #2	0 : Intelligent and Automatic PWM/Burst-PWM Transition - Most Energy Efficient (default) 1 : Forced PWM - No Burst Mode Allowed - Smallest Voltage Ripple

### R13 - Misc Control Register 2

Address	0x0D
Slave Address	N + 1
Туре	R/W
Reset Default	8h'00

Bit	Field Name	Description or Comment		
7:3	Unused	These bits are fixed to '0'. Reading these bits will result in a '00000'. Any data written into these		
		bits using the Register Write command is ignored.		
2	SW2 Slew	'0': No slew rate restriction on VCORE1 switcher output voltage (default)		
	Control	'1': Slew rate of VCORE1 switcher output voltage is reduced		
1	LDO4 Tracking	D': LDO4 at R1 register value in Active mode. LDO4 does not track V <sub>CORE2</sub> (default)		
	Select	'1': LDO4 tracks V <sub>CORE2</sub> with offset		
0	LDO4 Low I <sub>Q</sub> Bit	'0': Selects the higher bias point for LDO4 which results in 50mA operation (default)		
		'1': Selects the lower bias point for LDO4 which results in 5mA operation		
		See Table 3 for a more detailed explanation of this bit		

### LP5552 Operation

#### **GENERAL DESCRIPTION**

The LP5552 is a PowerWise Interface (PWI) 2.0 compliant energy management unit (EMU) for application or baseband processors in mobile phones and other portable equipment. It operates cooperatively with processors using National Semiconductor's Advanced Power Controller (APC) to provide Adaptive Voltage Scaling (AVS) which drastically improves efficiencies compared to conventional power delivery methods. The LP5552 consists of two high-efficiency switching DC/DC buck converters to supply two voltage scaling domains, and five LDOs for supplying additional support circuitry.

#### **VOLTAGE SCALING**

The LP5552 is designed to be used in a voltage scaling system to lower the power dissipation of the system. By scaling supply voltage with the clock frequency of a processor, dramatic power savings can be achieved. Two types of voltage scaling are supported, dynamic voltage scaling (DVS) and adaptive voltage scaling (AVS). Both Switcher 1 and Switcher 2 support AVS and DVS modes. DVS systems switch between pre-characterized voltages, which are paired to clock frequencies used for frequency scaling in the processor. AVS systems track the processor performance and optimize the supply voltage to the required performance. AVS is a closed loop system that provides process and temperature compensation such that for any given processor, temperature, or clock frequency, the minimum supply voltage is delivered.

#### **POWERWISE INTERFACE**

What follows is only a brief description of the parts of the PWI 2.0 spec that are relevant to the LP5552. Please see the PWI 2.0 spec for a complete description.

To support DVS and AVS, the LP5552 is programmable via the low-power, 2-wire PowerWise Interface (PWI). This serial interface controls the various voltages and states of all the regulators in the LP5552.

Both slaves in the LP5552 support the full PWI command set, other than the optional Extended Register Read and Write, as described in the PWI 2.0 specification:

- Core Voltage Adjust
- Reset
- Sleep
- Shutdown
- Wakeup
- Register Read
- Register Write
- Authenticate

The 2-wire PWI interface is composed of the SCLK and SPWI pins on the LP5552. SCLK is always an input to the LP5552 and should be driven by a PowerWise master in the system. The SCLK clock rate can operate from 32kHz – 15MHz. SPWI is the bi-directional serial data line. It can drive a 50pF line and meet timing standards for a 15MHz PWI bus. Both signals are referenced to the voltage present at V<sub>02</sub>, the LDO2 output voltage. Both signals contain an internal pull-down resistor of ~1MΩ, in accordance with the PWI 2.0 specification.

#### SLAVE ADDRESSING DESCRIPTION

PWI 2.0 supports up to 16 logical slaves in the same system. Four slave address bits are included at the start of every PWI communications frame to identify which slave is being targeted by the PWI master. The LP5552 contains 2 logical slaves in its package. The 3 MSBs of the LP5552's slave address are set by the SA1, SA2, and SA3 pins. They are actively decoded by the LP5552 on every transaction. The LSB of the slave address is hard-wired inside the LP5552. Slave 'N' will always be located at SA[0] = 0, and slave 'N+1' will always exist at SA[0] = 1. As an example, if we were to tie SA1 = SA3 = VDD and SA2 = GND in our system, then the LP5552's slave 'N' would be located at SA[3:0] = 0xA and slave 'N+1' would be SA[3:0] = 0xB.

#### CONTROL AND STATUS SIGNALS

The LP5552 implements all 3 of the PWI 2.0 control and status signals. ENABLE and RESETN are inputs to the LP5552 that allow for power-up and power-down sequencing, as well as resetting the EMU to a known state. Both ENABLE and RE-SETN must be a logic '1' during normal operation. PWROK is an indicator to the system that the LP5552 is in regulation and power is stable. Its output is dependent upon the state of the two slave devices. See *Table 1*, "PWROK Value Per Slave State," below for details. All 3 signals are asynchronous signals.

TABLE 1. PWROK Value Per Slave State				
		9	SLAVE (N+1)	

		SLAVE (N+1)			
		STARTUP	ACTIVE	SLEEP	SHUTDOWN
SLAVE (N)	STARTUP	0	1	1	0
	ACTIVE	1	1	1	1
	SLEEP	1	1	1	1
	SHUTDOWN	0	1	1	0

#### **General Purpose Outputs**

The LP5552 contains 3 digital output pins that can be used as the system designer sees fit. By default, they are configured as open-drain outputs, outputting a logic '0'. They can be changed to a push-pull CMOS output by clearing Slave 'N', R13[3]. In the open-drain configuration, they can be referenced to any voltage less than the VDD of the LP5552. The push-pull output mode will reference the high-side to the voltage of LDO2.



The Startup state is the default state for both slaves after reset. All regulators are off and PWROK output is a '0'.

The device will move to the Active state when the external ENABLE and RESETN signals are both pulled high. After the state transition completes, both slaves will be in the Active state, but each slave will maintain its own independent state thereafter.

The default, factory-programmed power-up sequence of the LP5552 can be seen in *Figure 2*. From the global ENABLE of the chip, there is ~80uS of time for powering on and stabilizing internal support circuitry. Once this time has expired, the start-up time slots begin. *Table 2* shows the time slots that each regulator begins in. Note that for the switchers, there is an additional ~75uS of set-up time from the beginning of the time slot until the soft-start ramp begins.



FIGURE 2. LP5552 Startup Timing

-P5552

#### TABLE 2. Factory Programmed Startup Time Slots

Time slot	Start time (µS)	Regulator(s)
0	0	LDO2
1	32	LDO5/AVS1
2	64	LDO1/AVS2
3	96	LDO3
4	128	LDO4

In the Active state, all regulators that are enabled are on, and their outputs are defined by their programmed register values. If the Active state has been reached from the Startup state, the regulators will be programmed to their default value. In the Active state, the PWI master has complete control over the LP5552's operation. The PWROK output is '1' if either slave is in this state.

The Sleep state is entered by issuing the Sleep command on the PWI bus. The core regulator of the addressed slave, and the associated memory LDO will both respond to the Sleep command. For the first 32uS after the command is decoded, the core regulator will transition to its zero-code value of 0.6V, and the LDO will move to its POR value of 1.25V. After the 32uS has expired, the core regulator will be turned off and the LDO will transition to its memory retention value as programmed in register R2. See *Figure 3*. LDO1, LDO2, and LDO5 are unaffected by the Sleep command and will maintain their programmed values. They may be turned off manually, if desired. The LP5552 will still respond to all PWI traffic as long as LDO2 remains active.



FIGURE 3. Sleep Behavior of Core and Memory

A slave may return to the Active state by issuing the Wakeup command. This will result in the core regulator turning on after a ~75uS delay and a soft-start ramp. It will wake up at its maximum value of 1.235V. The associated memory LDO will go to its default POR value of 1.25V until the core has reached the end of its soft-start period and then will transition to its programmed configuration (i.e., either tracking the core or to the value programmed in R1). See *Figure 4*. The PWROK output is '1' if either slave is in this state.



FIGURE 4. Wakeup Behavior of Core and Memory

The Shutdown command will place the addressed slave in the Shutdown state. This command may be issued to any slave in either the Active or Sleep states. All regulators within that state will turn off. The LP5552 holds out one exception to this rule. LDO1, LDO2, and LDO5 act as a shared resource between the two slave devices in the EMU. Therefore, placing just slave 'N' into Shutdown will not turn off these regulators even though their registers exist within that space. Slave 'N' can be in the Shutdown state, but as long as Slave 'N+1' is still in either Active or Sleep states, these shared LDOs will remain on, and PWI traffic will be decoded. Once the Shutdown command has been sent to both slaves, all regulators on the LP5552 will be turned off. The PWROK signal will be '0' if both slaves are in the Shutdown state. The only way to transition away from the Shutdown state is by disabling or resetting the LP5552. By taking the ENABLE pin or the RE-SETN pin low, the LP5552 will transition to the Startup state.

Power-down sequencing is not actively managed by the LP5552 logic, but can be handled by turning off regulators in the desired order within the application, prior to Shutdown.

#### PWM/BURST-PWM OPERATION

The switching regulators in the LP5552 have two modes of operation, pulse width modulation (PWM) and "Burst"-PWM. In PWM, the converter switches at 3.6MHz. Each period can be split into two cycles. During the first cycle, the high-side switch is on and the low-side switch is off. During this cycle, the inductor current is rising. In the second cycle, the high-side switch is off and the low-side switch is on causing the inductor current to decrease. The output ripple voltage is lowest in PWM mode. As the load current decreases, the converter efficiency becomes worse due to switching losses. The LP5552 will automatically transition to Burst mode at light load current levels. The exact transition point is dependent upon the present operating environment, and the mode assessment is constantly evaluated. The transition is approximately equal to:

$$I_{PWM/Burst-PWM} \approx \frac{V_{OUT}}{V_{IN}} \times \frac{V_{IN} - V_{OUT}}{2 \times L \times f_{S}}$$

In this mode, the output voltage will be allowed to coast with no switching action by the regulator. When the output voltage dips to 1% below nominal, the switches are enabled, the voltage is boosted back up to the programmed value, and the coast process repeats itself. If the user desires tighter control of the output voltage, at the expense of light-load efficiency, the switchers can be commanded to stay in PWM-only mode by setting bit 0 of R10 in the slave's registers.

#### CURRENT LIMITING

A current limit feature exists for all regulators to help protect the LP5552 and external components during overload conditions. The switcher's current limit feature will trip around 1.2A (typ). Once the fault has occurred and current limit has been entered, the switcher will not resume operation until the output current has decreased to a hysteretic low-level set point. Normal operation will proceed after the fault has been cleared. Likewise, the LDOs all implement current limit and will turn off their pass element when their trip point is reached. Please refer to the Electrical Characteristics section for details.

#### SOFT START

Both switching regulators implement a digital soft-start feature to limit in-rush current during the Startup to Active state transition. The voltage output of the switchers will be gradually increased to the default value of 1.235V. An unloaded switcher output will reach its final value in  $120\mu$ S (typ.) while a fully loaded switcher – 800mA -- will reach its output in  $135\mu$ S (typ). Because the LP5552 uses voltage increments to handle softstart, its turn-on time is less dependent on output capacitance and load current than regulators that gradually increase current limit to implement soft-start.

#### LDO2

The on-board LDO2 regulator has special significance to the LP5552. All digital data on the SCLK, SPWI, and the GPOx pins while in push-pull mode, is referenced to this voltage. This regulator is used internally to power the I/O drivers. As such, this regulator must be on in order to communicate with the LP5552. The user should ensure that this regulator does not go into dropout or PWI communication will most likely not

be possible. If it is not desirable to use this regulator in the system, the user can turn this regulator off by setting bit 4 of R10 in Slave 'N' during system initialization while back-driving the required I/O voltage onto the pin.

#### TRACKING, SLEW RATE LIMITING, AND LOW IQ BITS

There are 3 bits in each slave's R13 register that determine the performance and operational behavior of the  $V_{\rm COREx}$  and  $V_{\rm O3}/V_{\rm O4}$  outputs. Their significance and interaction is described below.

The Low I<sub>Q</sub> bit setting in R13, bit 0, of each slave allows the selection of a lower I<sub>Q</sub> bias point at the expense of decreased output current capability for V<sub>Q3</sub> and V<sub>Q4</sub>. At reset, the default setting is high I<sub>Q</sub> mode (i.e., bit 0 is cleared) which results in a 50mA output capability for the associated LDO. If bit 0 is set, the quiescent current draw of the part will decrease, but the output current capability of the associated LDO will drop to 5mA. Setting V<sub>Q3</sub> and V<sub>Q</sub>4 up for low I<sub>Q</sub> mode is useful in situations where just a trickle of current is required, such as when maintaining some type of low-power memory.

The Tracking bit, bit 1 in R13, determines whether or not the LDO3 voltage will track the  $V_{CORE1}$  voltage in Slave 'N'. Slave 'N+1' has its own tracking bit which will determine whether LDO4 tracks  $V_{CORE2}$ . Each slave device can be independently configured to tracking or independent mode. When set to operate independently, LDO3 and LDO4 will maintain a voltage output equal to the programmed value of R1 while in the Active state. When set to operate in tracking mode, LDO3 and LDO4 will track the output voltage of their associated switcher, attempting to maintain approximately a 25mV positive offset.

There is some interaction between the Low  $I_Q$  and Tracking bits based on the state of the slave device, and that is detailed in the following table:

	Input		Output
Tracking, R13[1]	Low I <sub>Q</sub> , R13[0]	State	LDO3/LDO4 Capability
0	0	Active	50mA
0	0	Sleep	50mA
0	1	Active	5mA
0	1	Sleep	5mA
1	0	Active	50mA
1	0	Sleep	50mA
1	1	Active	50mA
1	1	Sleep	5mA

#### TABLE 3. Tracking, IQ Bit, Slave State Truth Table

The final bit, the Slew Rate Limiting bit (R13[2]), places a limit on how fast the output voltage of the V<sub>COREx</sub> regulators can change. If slew rate limiting is not enabled while in tracking mode (i.e., R13[2] is cleared), then the switcher will achieve its new programmed value faster than the tracking LDO can change its output. By setting the Slew Rate Limiting bit, the LP5552 will attempt to keep the positive offset of the tracking LDO in relation to the V<sub>COREx</sub> output.

For AVS systems, the expected configuration is to have all 3 bits, R13[2:0] set to '1'. It generally will not make sense to set

the Slew Rate Limiting bit while not in tracking mode. Setting all 3 bits will result in a system which has the following properties:

- 1. The tracking LDO will maintain positive offset from V<sub>COREx</sub> in Active state.
- 2. Tracking LDO will be 50mA output capable in Active state, and 5mA capable in Sleep state.

### **Application Hints**

The power dissipated in the input capacitor is given by:

#### SWITCHERS

#### **Input Capacitors**

The input capacitor to a switching regulator supplies the AC switching current drawn from the switching action of the internal power FETs. The input current of a buck converter is discontinuous, so the ripple current supplied by the input capacitor is large. The input capacitor must be rated to handle this current:

$$I_{\text{RMS}_{\text{CIN}}} = I_{\text{OUT}} \frac{\sqrt{V_{\text{OUT}} \times (V_{\text{IN}} - V_{\text{OUT}})}}{V_{\text{IN}}}$$
(A)

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$$\mathsf{P}_{\mathsf{D}_{\mathsf{CIN}}} = \mathsf{I}^{2}_{\mathsf{RMS}_{\mathsf{CIN}}} \times \mathsf{R}_{\mathsf{ESR}_{\mathsf{CIN}}}(\mathsf{W})$$

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The input capacitor must be rated to handle both the RMS current and the dissipated power. A  $10\mu$ F ceramic capacitor, rated to handle at least 10V, is recommended for each PVD-Dx/PGNDx pair.

#### Inductor

A 1 $\mu$ H inductor should be used for the switchers' output filter. The inductor should be rated to handle the peak load current plus the ripple current:

 $I_{L(MAX)} = I_{LOAD(MAX)} + \Delta i_{L(MAX)}$ 

$$= I_{LOAD(MAX)} + \frac{D \times (V_{IN(MAX)} - V_{OUT})}{2 \times L \times f_{S}}$$
$$= I_{LOAD(MAX)} + \frac{D \times (V_{IN(MAX)} - V_{OUT})}{7.2} (A),$$
$$\begin{cases} f_{S} = 3.6 \text{ MHz} \\ L = 1.0 \text{ }\mu\text{H} \end{cases}$$

#### **Suggested Inductors and Their Suppliers**

Model	Vendor	Dimensions LxWxH (mm)	DCR (Typical)
LPS3010-102	Coilcraft	3.0 x 3.0 x 1.0	<b>85m</b> Ω
LQM31PN1R0MC0	muRata	3.2 x 1.6 x 0.5	140mΩ

#### **Output Capacitors**

The switchers in the LP5552 are designed to be used with  $10\mu$ F of capacitance in the output filter. It is recommended that a  $10\mu$ F ceramic capacitor, rated to handle at least 10V, and comprised of X5R dielectric material, be chosen. The output capacitor of a switching regulator absorbs the AC ripple current from the inductor and provides the initial response to a load transient. The ripple voltage at the output of the converters is the product of the ripple current flowing through the output capacitor and the impedance of the capacitor. The impedance of the capacitor can be dominated by capacitive, resistive, or inductive elements within the capacitor or the

PCB interconnect, depending upon the frequency of the ripple current. Ceramic capacitors are predominantly used in portable systems and have very low ESR and should remain capacitive given good PCB layout practices. The switcher peak-to-peak output voltage ripple in steady state can be calculated as:

$$V_{PP} = I_{LPP} (R_{ESR} + \frac{1}{F_{S} \times 8 \times C_{OUT}})$$

#### Suggested Switcher Output Capacitors and Their Suppliers

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Model	Vendor	Value	Туре	Voltage	Case Size (Height)
GRM219R61A106KE44	muRata	10µF	Ceramic, X5R	10V	0805 (0.85mm)
LMK212BJ106KD	Taiyo Yuden	10µF	Ceramic, X5R	10V	0805 (0.85mm)

#### A NOTE ABOUT CAPACITORS

Capacitors are typically specified by their manufacturers as a particular value +/-X%. These specified values are only valid for a particular test condition that is often not applicable to the final application circuit. If you were to take a ceramic 10 $\mu$ F capacitor in 0805 package and measure it with an LCR meter, a typical result would be around 7 $\mu$ F. This is before you even

insert the capacitor into the application circuit. Capacitance will decrease with increasing frequency and DC bias point, and will generally vary with temperature. A typical 6.3V, 10 $\mu$ F, 0603 capacitor may only be providing 4 - 5 $\mu$ F of capacitance when used as the output capacitor in the switching regulators' loop filter. It is highly recommended that measurements be done on your selected capacitor(s) to ensure you have the proper amount of capacitance.

#### LDOs

#### Input Capacitors

While not mandatory, it is highly recommended that some input capacitance be provided for the DVDDx and AVDDx pins. Typical values may be in the  $0.1 - 1.0\mu$ F range. These capacitors will provide bypass for the LP5552 control electronics and LDOs.

#### **Output Capacitors**

The output capacitor of an LDO sets a low frequency pole and a high frequency zero in the control loop of an LDO, as well as providing the initial response for a load transient. The capacitance and the equivalent series resistance (ESR) of the capacitor must be within a specified range to meet stability requirements. The LDOs in the LP5552 are designed to be used with ceramic output capacitors. The following table can be used to select suitable output capacitors:

	Output Capacitance Range	ESR Range				
	(Recommended Typical Value)					
LDO1	1.0μF — 20μF (2.2μF)	5mΩ - 500mΩ				
LDO2	2.0μF — 20μF (4.7μF)	5mΩ - 500mΩ				
LDO3	0.7μF — 2.2μF (1.0μF)	$5m\Omega$ - $500m\Omega$				
LDO4	0.7μF — 2.2μF (1.0μF)	$5m\Omega$ - $500m\Omega$				
LDO5	2.0μF — 20μF (4.7μF)	5mΩ - 500mΩ				

#### LDO Output Capacitor Selection Guide

#### **Dropout Voltages**

All linear regulators are subject to dropout. Dropout Voltage is the minimum voltage required across the regulator (V<sub>IN</sub> - V<sub>OUT</sub>) to maintain a constant, specified output voltage. The LP5552 has a V<sub>IN</sub> range of 2.7V – 4.8V. V<sub>O1</sub>, V<sub>O3</sub>, and V<sub>O4</sub> cannot be programmed to a level that would make dropout a factor. However, V<sub>O2</sub> and V<sub>O5</sub> can reach as high as 3.3V on their outputs. Both of those regulators have a dropout voltage of 260mV (MAX). To ensure proper operation of those regulators, the user should ensure that V<sub>IN</sub>  $\geq$  (V<sub>Ox-PROGRAMMED</sub> + 260mV). If a regulator does go into dropout, the output voltage will start to track the input: V<sub>O</sub> = V<sub>IN</sub> - V<sub>DROPOUT</sub>. Also, the PSRR will go to zero, meaning any noise on the input will be seen at the output.

#### **BOARD LAYOUT CONSIDERATIONS**

PC board layout is an important part of DC-DC converter design. Poor board layout can disrupt the performance of a DC-DC converter and surrounding circuitry by contributing to EMI, ground bounce, and resistive voltage loss in the traces. These can send erroneous signals to the DC-DC converter IC, resulting in poor regulation or instability. It is highly recommended that the user consult Application Note AN-1610 for detailed guidelines and best methods for PCB layout of the LP5552. It is also recommended that the user reference AN-1112 for information on the micro SMD package and its requirements.



LP5552

### Notes

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